## Form 1449 (Modified)

**Information Disclosure** Statement By Applicant

(Use Several Sheets if Necessary)

Atty Docket No.

NOVL085/NVLS-2875 Applicant:

Application No.: 10/785,235

Wang et al.

Filing Date

February 23, 2004

Group

## **II.S. Patent Documents**

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Examiner						Sub-	Filing
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	A8	· ·					
	A9						
	A10						
	A11						

Foreign Patent or Published Foreign Patent Application

Examiner		Document	Publication	Country or		Sub-	Trans	slation
Initial	No.	No.	Date	Patent Office	Class	class	Yes	No
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## Other Documents

Examiner						
Initial	No:	Author, Title, Date, Place (e.g. Journal) of Publication				
FLT	C1		is", U.S. Patent No. 10/6	s From Porous Low-K Films 672,305, filed September 26,		
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Examiner	/Fe	rnando L. Toledo/	Date Considered	11/14/2006		

Examiner: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

| Atty Docket No. | Application No.:
NOVLP085/NVLS-002875	Unassigned 10/745, 235	
Information Disclosure	Statement By Applicant	Wang et al.
(Use Several Sheets if Necessary)	HEREWITH 2/23/04	Unassigned

**U.S. Patent Documents** 

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Foreign Patent or Published Foreign Patent Application

Examiner		Document	Publication	Country or		Sub-	Trans	Translation	
Initial	No.	No.	Date	Patent Office	Class	class	Yes	No	
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FLT	C2	Wu et al., "Use of Multifunctional SI-Based Oligomer/Polymer for the Surface Modification of Nanoporous Silica Films," U.S. Patent Application Publication No. US2002/0001973, Published January 3, 2002, 13 Pages
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Information Disclosure
Statement By Applicant

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NOVLP085/NVLS-002875

Applicant:
Wang et al.
Filing Date
HEREWITH

Application No.:

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Application No.:

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